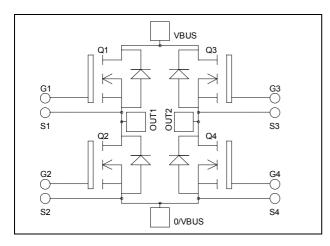


# Full - Bridge MOSFET Power Module

$$\begin{split} V_{DSS} &= 1000 V \\ R_{DSon} &= 180 m \Omega \ typ \ @ \ Tj = 25^{\circ} C \\ I_D &= 43 A \ @ \ Tc = 25^{\circ} C \end{split}$$



0/VBU

### Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### **Features**

- Power MOS 7<sup>®</sup> FREDFETs
  - Low R<sub>DSon</sub>
  - Low input and Miller capacitance
  - Low gate charge
  - Fast intrinsic reverse diode
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

#### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		1000	V
Ţ	Continuous Drain Current	$T_c = 25$ °C	43	
$I_D$	Continuous Drain Current	$T_c = 80$ °C	33	Α
$I_{DM}$	Pulsed Drain current		172	
$V_{GS}$	Gate - Source Voltage		±30	V
R <sub>DSon</sub>	Drain - Source ON Resistance		210	mΩ
$P_{D}$	Maximum Power Dissipation $T_c = 25^{\circ}C$		780	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)		25	A
$E_{AR}$	Repetitive Avalanche Energy		50	m I
$E_{AS}$	Single Pulse Avalanche Energy		3000	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings @ $T_j = 25$ °C unless otherwise specified

#### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$	$T_j = 25$ °C			200	^	
		$V_{GS} = 0V, V_{DS} = 800V$	$T_j = 125$ °C			1000	μΑ	
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 21.5A$			180	210	mΩ	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 5mA$		3		5	V	
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	7			±150	nA	

**Dynamic Characteristics** 

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		10.4		
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		1.76		nF
$C_{rss}$	Reverse Transfer Capacitance	f=1MHz		0.32		
$Q_{\rm g}$	Total gate Charge	$V_{GS} = 10V$		372		
$Q_{gs}$	Gate – Source Charge	$V_{\rm Bus} = 500 V$		48		nC
$Q_{\mathrm{gd}}$	Gate – Drain Charge	$I_{D} = 43A$		244		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		18		
$T_{r}$	Rise Time	$V_{GS} = 15V$		12		ma
$T_{d(off)}$	Turn-off Delay Time	$\begin{cases} V_{\text{Bus}} = 670V \\ I_{\text{D}} = 43A \end{cases}$		155		ns
$T_{\mathrm{f}}$	Fall Time	$R_G = 2.5\Omega$		40		
$E_{on}$	Turn-on Switching Energy	Inductive switching @ 25°C		1800		т
$E_{\text{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 43A, R_G = 2.5\Omega$		1246		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		2846		т
$E_{\text{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 43A, R_G = 2.5\Omega$		1558	·	μJ

#### Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
$I_S$	Continuous Source current		$Tc = 25^{\circ}C$			43	Α
	(Body diode)		$Tc = 80^{\circ}C$			33	Λ
$V_{\mathrm{SD}}$	Diode Forward Voltage	$V_{GS} = 0V$ , $I_S = -43A$	1			1.3	V
dv/dt	Peak Diode Recovery					18	V/ns
t <sub>rr</sub>	Reverse Recovery Time		$T_j = 25$ °C			320	ns
	reverse recovery Time	$I_S = -43A$ $V_R = 670V$	$T_j = 125$ °C			650	113
Q <sub>rr</sub>	Reverse Recovery Charge	$di_S/dt = 200A/\mu s$	$T_j = 25$ °C		7.2		μС
			$T_j = 125$ °C		19.5		μΟ

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

 $I_S \leq \text{- 43A} \qquad \text{di/dt} \leq 700 \text{A/} \mu \text{s} \qquad V_R \leq V_{DSS} \qquad T_j \leq 150 ^{\circ} \text{C}$ 

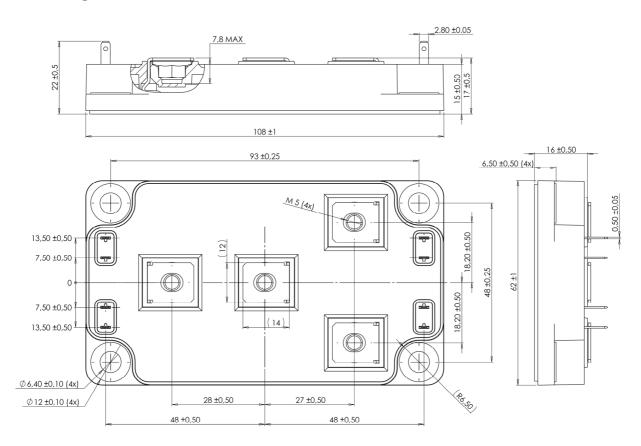
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### Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
$R_{thJC}$	Junction to Case Thermal Resistance					0.16	°C/W
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range		-40		150	°C	
$T_{STG}$	Storage Temperature Range			-40			125
$T_{\rm C}$	Operating Case Temperature			-40			100
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

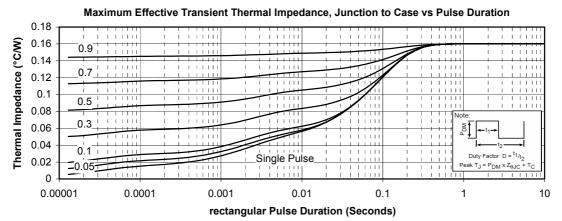
### SP6 Package outline (dimensions in mm)

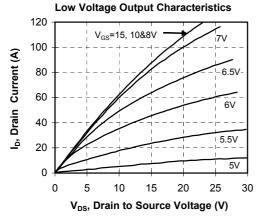


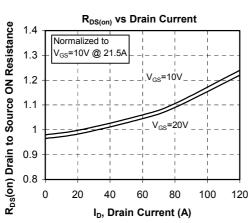
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

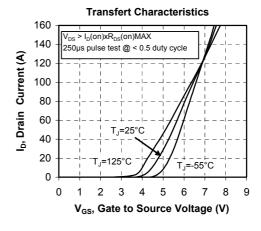


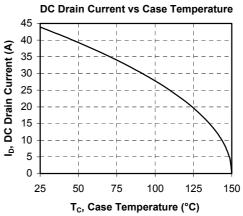
### **Typical Performance Curve**



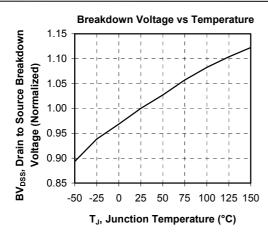


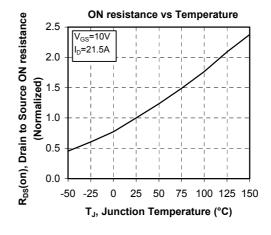


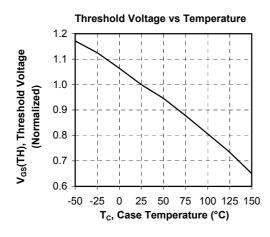


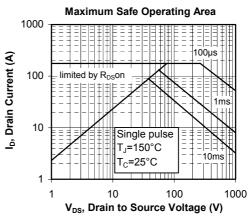


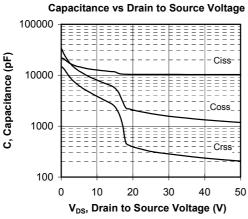


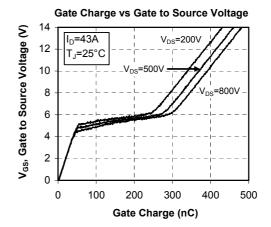




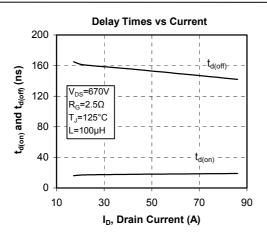


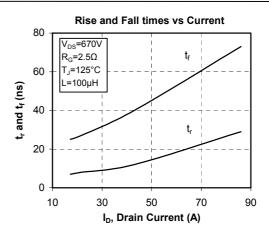


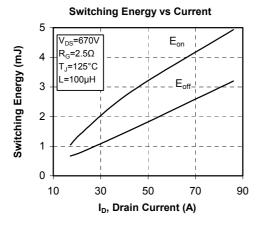


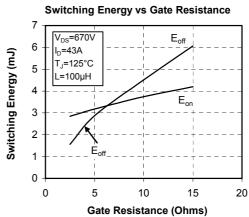


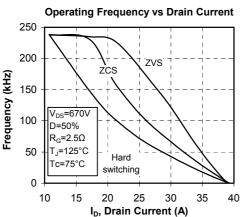


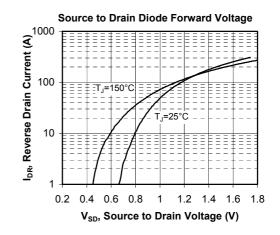














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